

# RM600DY-66S

HIGH POWER SWITCHING USE  
INSULATED TYPE

High Voltage Diode Module

## RM600DY-66S



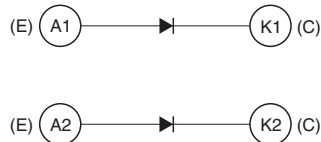
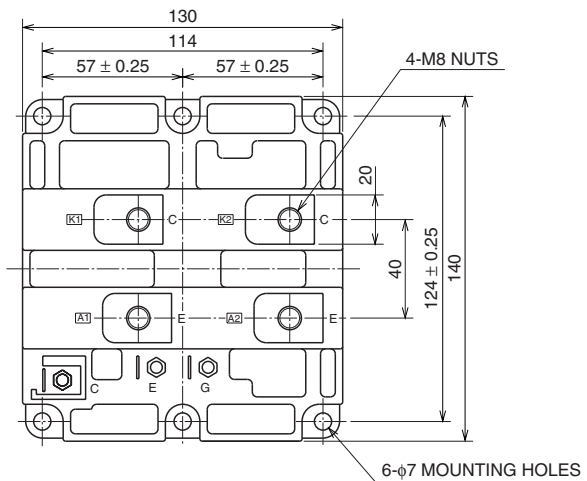
- IF ..... 600A
- VRRM ..... 3300V
- Insulated Type
- 2-element in a Pack
- Copper Baseplate

## APPLICATION

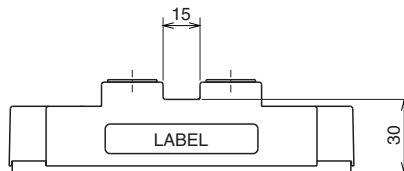
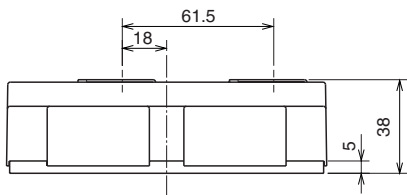
Traction drives, High Reliability Converters / Inverters, DC choppers

## OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



CIRCUIT DIAGRAM



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**MAXIMUM RATINGS**

Symbol	Item	Conditions	Ratings	Unit
VRRM	Repetitive peak reverse voltage	T <sub>j</sub> = 25 °C	3300	V
V <sub>RRM</sub>	Non-repetitive peak reverse voltage	T <sub>j</sub> = 25 °C	3300	V
V <sub>R(DC)</sub>	Reverse DC voltage	T <sub>j</sub> = 25 °C	2200	V
I <sub>F</sub>	DC forward current	T <sub>c</sub> = 25 °C	600	A
I <sub>FSM</sub>	Surge forward current	T <sub>j</sub> = 25 °C start, t <sub>w</sub> = 8.3 ms Half sign wave	4800	A
i <sup>2</sup> t	Current-squared, time integration	T <sub>j</sub> = 25 °C start, t <sub>w</sub> = 8.3 ms Half sign wave	96	kA <sup>2</sup> s
V <sub>iso</sub>	Isolation voltage	Charged part to the baseplate RMS sinusoidal, 60Hz 1min.	6000	V
T <sub>j</sub>	Junction temperature	—	-40 ~ +150	°C
T <sub>op</sub>	Operating temperature	—	-40 ~ +125	°C
T <sub>stg</sub>	Storage temperature	—	-40 ~ +125	°C

**ELECTRICAL CHARACTERISTICS**

Symbol	Item	Conditions	Limits			Unit
			Min	Typ	Max	
I <sub>RRM</sub>	Repetitive reverse current	V <sub>RM</sub> = V <sub>RRM</sub>	T <sub>j</sub> = 25 °C	—	4.0	mA
			T <sub>j</sub> = 125 °C	—	15	
V <sub>FM</sub>	Forward voltage (Note 1)	I <sub>F</sub> = 600 A	T <sub>j</sub> = 25 °C	—	4.55	V
			T <sub>j</sub> = 125 °C	—	—	
t <sub>rr</sub>	Reverse recovery time	V <sub>R</sub> = 1650 V, I <sub>F</sub> = 600 A di/dt = -1200 A/μs L <sub>s</sub> =200nH, T <sub>j</sub> = 125 °C	—	0.75	—	μs
I <sub>rr</sub>	Reverse recovery current		—	450	—	A
Q <sub>rr</sub>	Reverse recovery charge		—	300	—	μC
E <sub>rec</sub>	Reverse recovery energy (Note 2)		—	0.23	—	J/P

Note 1. It doesn't include the voltage drop by internal lead resistance.  
2. E<sub>rec</sub> is the integral of 0.1V<sub>R</sub>x 0.1I<sub>rr</sub>x dt.

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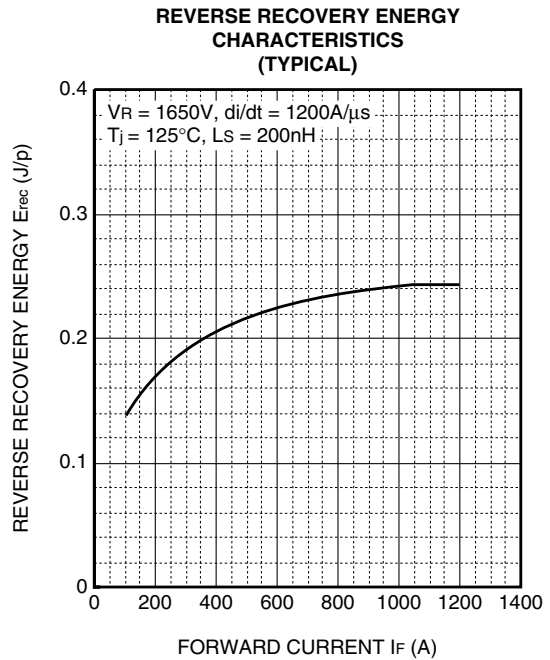
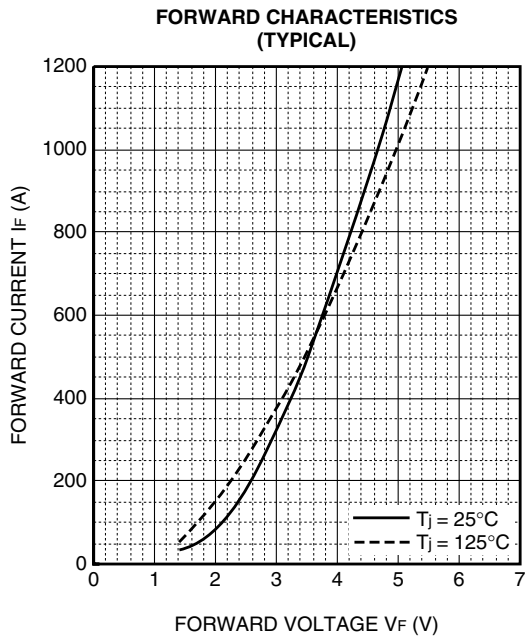
**THERMAL CHARACTERISTICS**

Symbol	Item	Conditions	Limits			Unit
			Min	Typ	Max	
Rth(j-c)	Thermal resistance	Junction to case (per 1/2 module)	—	—	48.0	K/kW
Rth(c-f)	Contact thermal resistance	Case to Fin, $\lambda_{grease} = 1W/m\cdot K$ D(c-f)=100 $\mu$ m, (per 1/2 module)	—	24.0	—	K/kW

**MECHANICAL CHARACTERISTICS**

Symbol	Item	Conditions	Limits			Unit
			Min	Typ	Max	
Mt	Mounting torque	M8: Main terminals screw	6.67	—	8.24	N·m
Ms		M6: Mounting screw	2.84	—	3.43	N·m
m	Mass	—	—	1.5	—	kg

**PERFORMANCE CURVES**

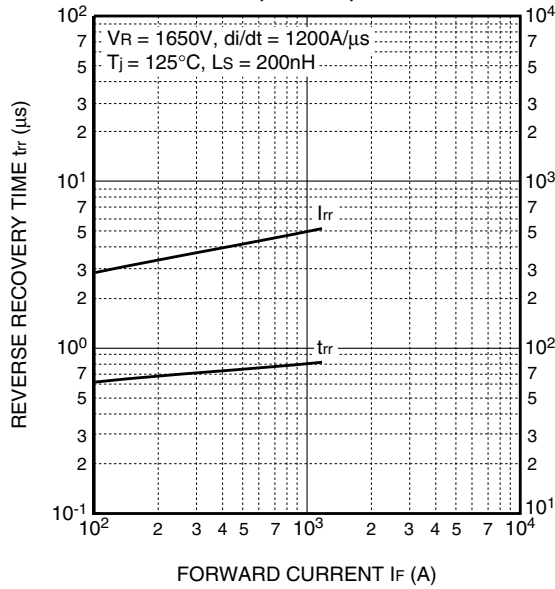


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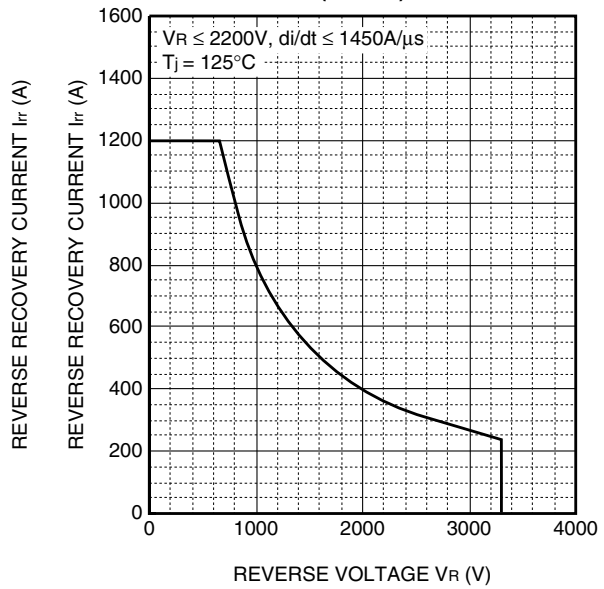
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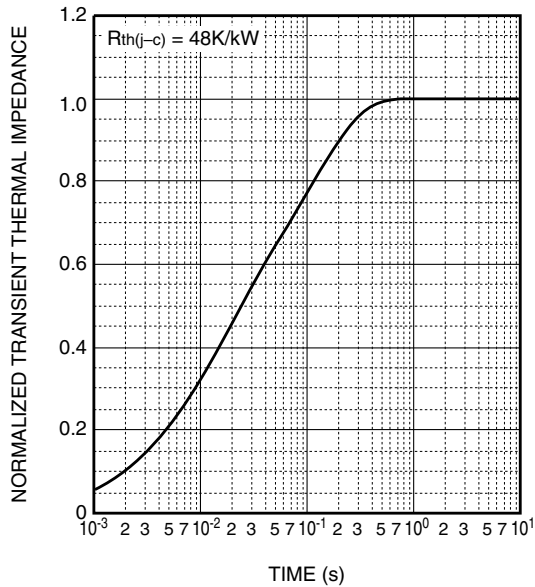
**REVERSE RECOVERY CHARACTERISTICS (TYPICAL)**



**REVERSE RECOVERY SAFE OPERATING AREA (RRSOA)**



**TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS**



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